

Optocoupler

1. Description

The SL214N is a four-channel optocoupler consisting of light-emitting diodes and phototransistors, packaged in SSOP16 format.

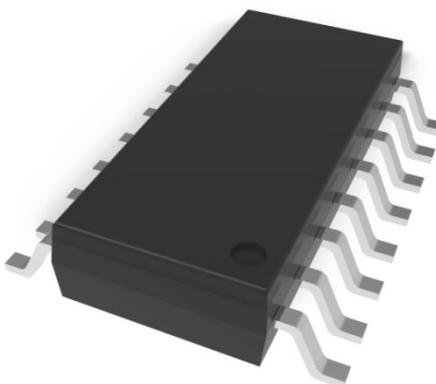
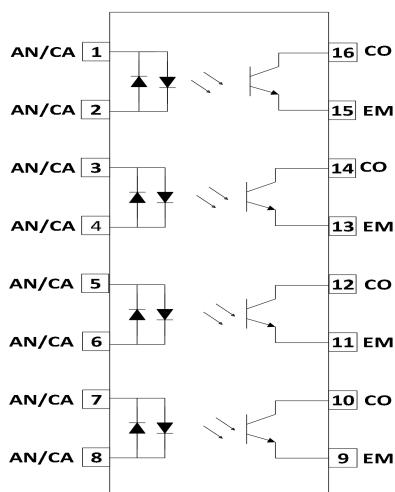
2. Features

- Current Transfer Ratio (CTR) range: $\geq 20\%$
- Input-output isolation voltage ($V_{iso}=3750\text{Vrms}$)
- Collector-emitter breakdown voltage ($BVCEO \geq 80\text{V}$)
- Creepage distance $\geq 5\text{mm}$
- External electrical clearance $\geq 5\text{mm}$
- DTI $\geq 0.3\text{mm}$

3. Applications

- Switching power supply, smart meter
- Industrial control, measuring instruments
- Office equipment, such as photocopiers
- Household appliances, such as air conditioners, fans, water heaters, etc

4. Structural schematics and packaging



5.Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Value	Unit
Transmitter	Forward Current	I _F	±50	mA
	Power dissipation	P _D	70	mW
	Derating Factor (Above T _A =100°C)	P _{DD}	2.9	mW/°C
	Thermal resistance (junction-ambient)	R _{thJ-A}	325	°C/W
	Thermal resistance (junction-case)	R _{thJ-C}	200	°C/W
Receiver	Collector power dissipation	P _C	150	mW
	Collector current	I _C	50	mA
	Collector-emitter voltage	V _{CEO}	80	V
	Emitter-collector voltage	V _{ECO}	7	V
Total power dissipation		P _{tot}	500	mW
Transient Voltage Suppression (TVS) capability		V _{iso}	3750	Vrms
Operating temperature		T _{opr}	-55~+100	°C
Storage temperature		T _{stg}	-55~+125	°C
Soldering temperature		T _{sol}	260	°C

6.Electrical characteristics (Ta=25°C)

Parameter		Symbol	Conditions	Min.	Type	Max.	Unit
Transmitter	Forward voltage	V _F	I _F =±20mA	-	1.2	1.4	V
	Terminal capacitance	C _t	V=0, f=1kHz	-	30	250	pF
Receiver	Collector dark current	I _{CEO}	I _F =0mA, V _{CE} =20V	-	-	100	nA
	Collector-emitter breakdown voltage	BV _{CEO}	I _C =0.1mA, I _F =0	80	-	-	V
	Emitter-collector breakdown voltage	BV _{ECO}	I _E =10μA, I _F =0	7	-	-	V
Transmission characteristics	Current transfer ratio	CTR*	I _F =±1mA, V _{CE} =5V	20	-	300	%
	Collector-emitter saturation voltage drop	V _{CE(sat)}	I _F =±20mA, I _C =1mA	-	0.1	0.2	V
	Isolation resistance	R _{ISO}	DC500V, 40~60%R.H.	5x10 ¹⁰	10 ¹¹	-	Ω
	Isolation capacitor	C _f	V=0, f=1MHz	-	0.6	1.0	pF
	Cut-off frequency	F _c	V _{CE} =5V, I _C =2mA, R _L =100Ω, -3dB	-	80	-	kHz
	Rise time	T _r	V _{CE} =2V, I _C =2mA, R _L =100Ω	-	-	18	μs
	Fall time	T _f	V _{CE} =2V, I _C =2mA, R _L =100Ω	-	-	18	μs

* CTR=I_C/I_F x 100%

7.Typical photoelectric characteristic curves

Fig.1 Test circuits

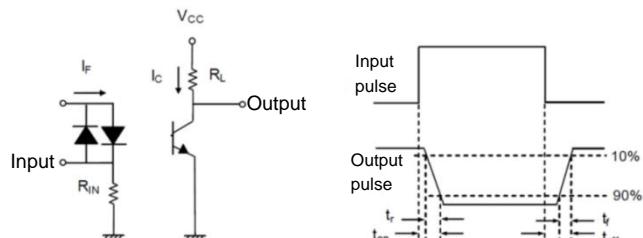


Fig.2 Relative Current Transfer Ratio vs. Forward Current

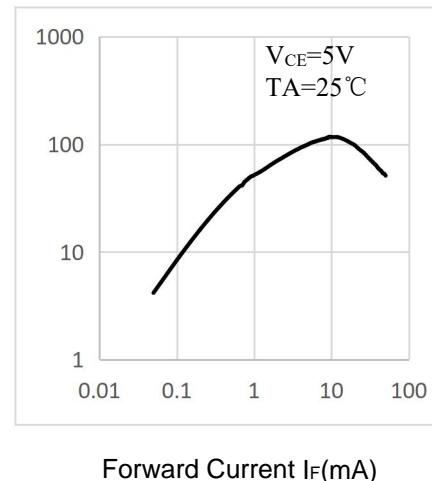


Fig.3 Forward Current vs. Forward Voltage

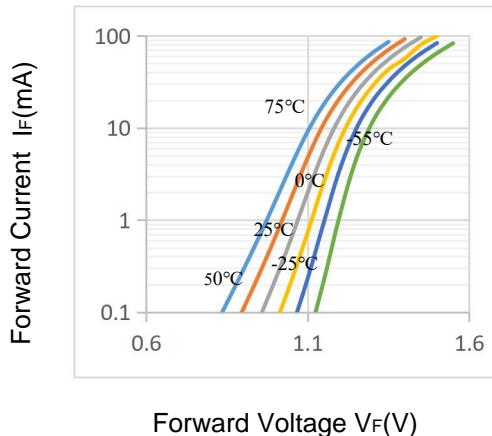


Fig.4 Collector Current vs. Collector-Emitter Voltage

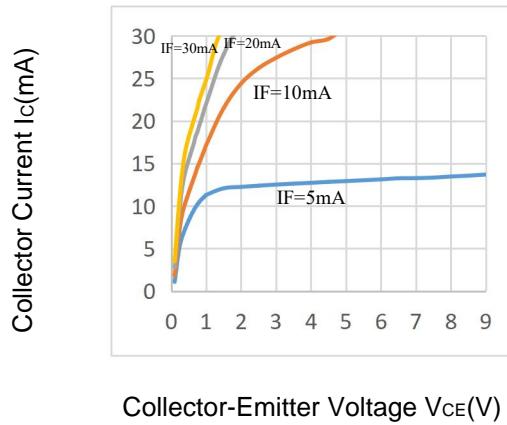


Fig.5 Relative Current Transfer Ratio vs. Ambient Temperature

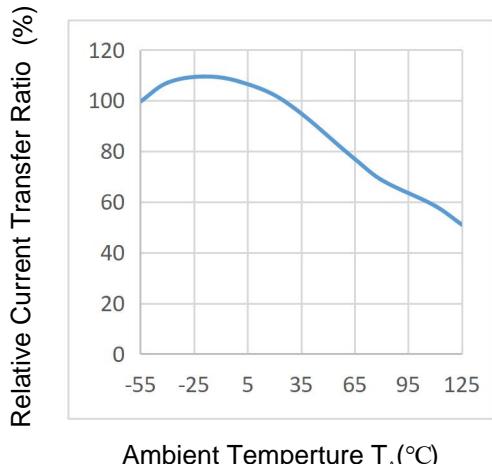


Fig.6 Saturation Pressure Drop vs. Ambient Temperature

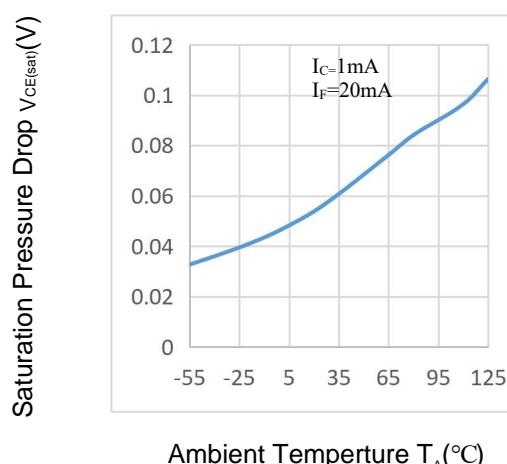


Fig.7 Collector Dark Current vs. Ambient Temperature

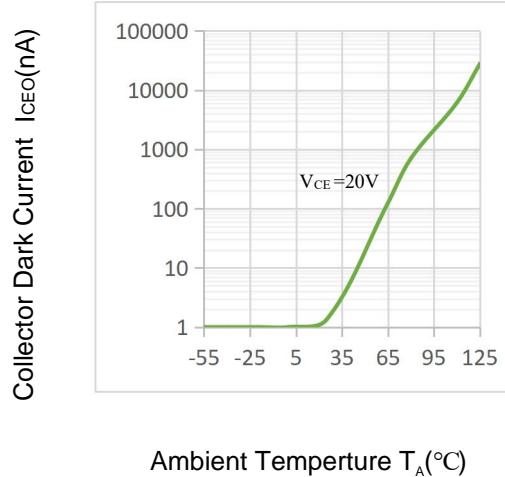


Fig.8 Response Time vs. Load Resistance

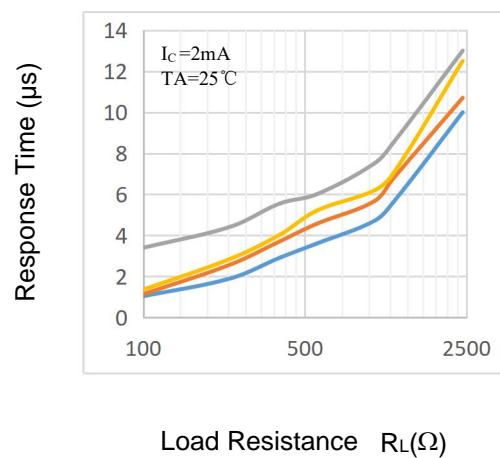


Fig.9 Frequency Response

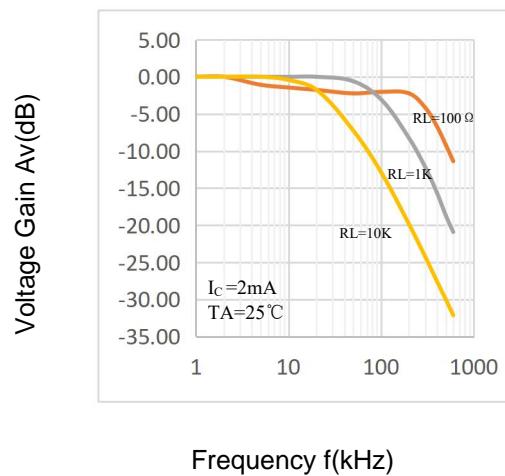
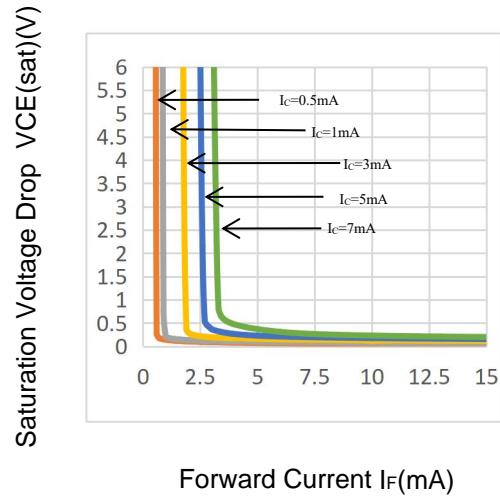
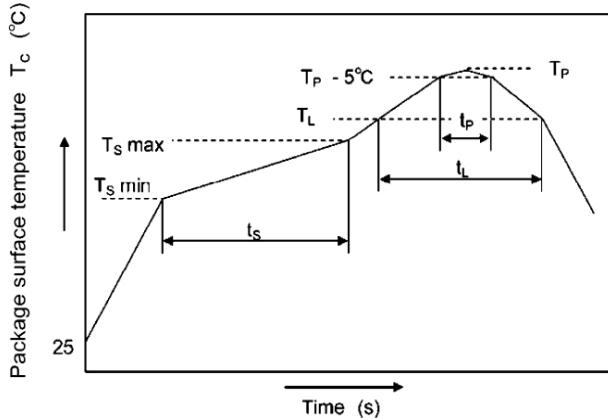


Fig.10 Saturation Voltage Drop vs. Forward Current



8.Reflow temperature curves



	Symbol	Min	Max	Unit
Preheat temperature	T_s	150	200	$^{\circ}\text{C}$
Preheat time	t_s	60	120	s
Ramp-up rate (T_L to T_p)			3	$^{\circ}\text{C/s}$
Liquidus temperature	T_L	217		$^{\circ}\text{C}$
Time above T_L	t_L	60	150	s
Peak temperature	T_p	260		$^{\circ}\text{C}$
Time during which T_c is between ($T_p - 5$) and T_p	t_p	30		s
Ramp-down rate (T_p to T_L)		6		$^{\circ}\text{C/s}$

Note:

1. It is recommended to perform reflow soldering under the specified temperature and time conditions, with no more than three cycles.
2. Manual soldering with a soldering iron
 - A. Manual soldering with a soldering iron is only intended for product rework or sample testing.
 - B. Manual soldering requirements: Temperature of $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$, duration ≤ 3 seconds.

9.Package dimensions

SSOP-16

Unit:mm

